

High voltage fast-switching PNP power transistor

Features

- High voltage capability
- Very high switching speed

Application

■ Electronic ballast for fluorescent lighting

Description

The device is manufactured using high voltage multi epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA. The ST93003 is expressly designed for a new solution to be used in compact fluorescent lamps, where it is coupled with the ST83003, its complementary NPN transistor.

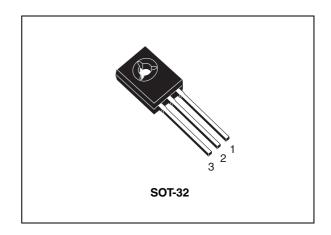


Figure 1. Internal schematic diagram

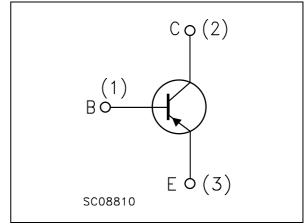


Table 1. Device summary

Order code	Order code Marking		Packaging	
ST93003 93003		SOT-32	Bag	

Contents ST93003

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ST93003 Electrical ratings

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	-500	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-400	V
V _{EBO}	Emitter-base voltage ($I_C = 0$, $I_B = -0.75$ A, $t_p < 10 \mu s$)	V _{(BR)EBO}	>
I _C	Collector current	-1.5	Α
I _{CM}	Collector peak current (t _p < 5 ms)	-3	Α
I _B	Base current	-0.75	Α
I _{BM}	Base peak current (t _p < 5 ms)	-1.5	Α
P _{TOT}	Total dissipation at T _c = 25 °C	40	W
T _{STG}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thJC}	Thermal resistance junction-case max	3.1	°C/W

Electrical characteristics ST93003

2 Electrical characteristics

 $T_{case} = 25$ °C unless otherwise specified

Table 4. On/off states

Symbol	Parameter	Test conditions	Value			Unit
Symbol			Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = -500 V V _{CE} = -500 V, T _C = 125 °C			-1 -5	mA mA
V _{(BR)EBO}	Emitter-base breakdown voltage (I _C = 0)	I _E = -10 mA	-5		-10	V
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = -10 mA	-400			V
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_C = -0.5 \text{ A}, I_B = -0.1 \text{ A}$ $I_C = -0.35 \text{ A}, I_B = -50 \text{ mA}$			-0.5 -0.5	V V
V _{BE(sat)} (1)	Base-emitter saturation voltage	I _C = -0.5 A, I _B = -0.1 A			-1	V
h _{FE} ⁽¹⁾	DC current gain	$I_C = -10 \text{ mA}, V_{CE} = -5 \text{ V}$ $I_C = -0.35 \text{ A}, V_{CE} = -5 \text{ V}$ $I_C = -1 \text{ A}, V_{CE} = -5 \text{ V}$	10 16 4	25	32	
t _r t _s	Resistive load Rise time Storage time Fall time	I_{C} = -0.35 A, V_{CC} = 125 V, I_{B1} = -70 mA, I_{B2} = 70 mA $t_{p} \ge$ 25 μ s see <i>Figure 14</i>	1.5	90 2.2 0.1	2.9	ns µs µs
t _s	Inductive load Storage time Fall time	I_{C} = -0.5 A, I_{B1} = -0.1 A, $V_{BE(off)}$ = 5 V, L = 10 mH, V_{clamp} = 300 V see <i>Figure 13</i>		400 40		ns ns
E _{sb}	Avalanche energy	L = 4 mH, C = 1.8 nF, I _{BR} = 2.5 A, 25 °C < T _C < 125 °C	12			mJ

^{1.} Pulse test: pulse duration $300 \le \mu s$, duty cycle $\le 2 \%$

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

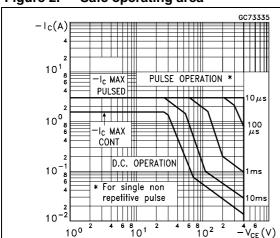


Figure 3. Derating

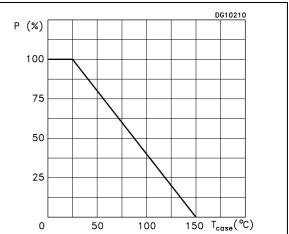


Figure 4. DC current gain $(V_{CE} = -5 V)$

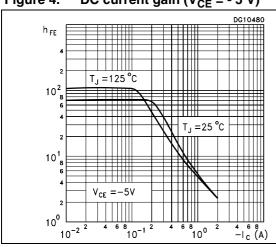


Figure 5. DC current gain $(V_{CE} = -1 V)$

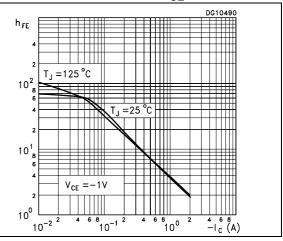
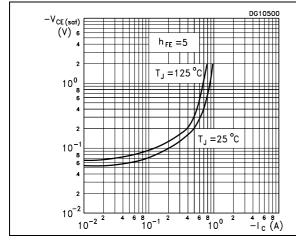
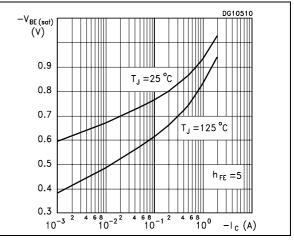


Figure 6. Collector emitter saturation voltage Figure 7. Base emitter saturation voltage

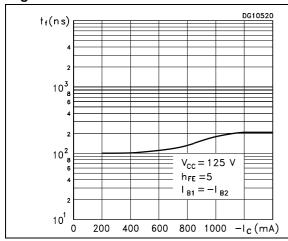




Electrical characteristics ST93003

Figure 8. Resistive load fall time

Figure 9. Resistive load storage time



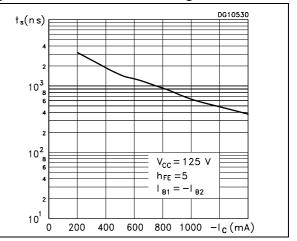
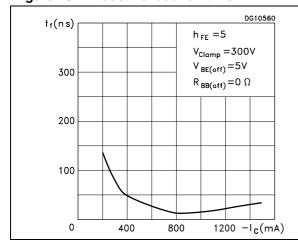


Figure 10. Inductive load fall time

Figure 11. Inductive load storage time



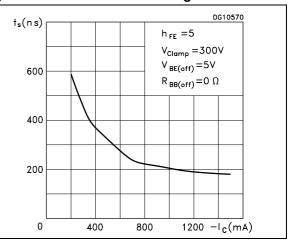
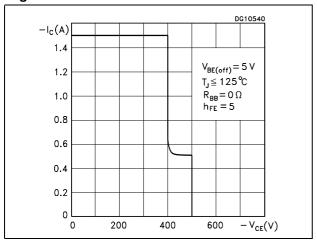


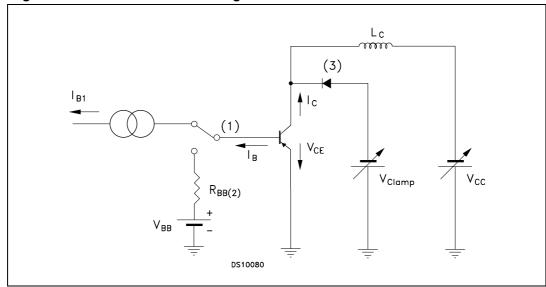
Figure 12. Reverse biased SOA



ST93003 Test circuits

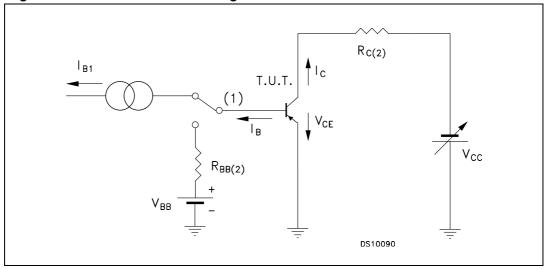
3 Test circuits

Figure 13. Inductive load switching



- 1. Fast electronic switch
- 2. Non-inductive resistor
- 3. Fast recovery rectifier

Figure 14. Resistive load switching



- 1. Fast electronic switch
- 2. Non-inductive resistor

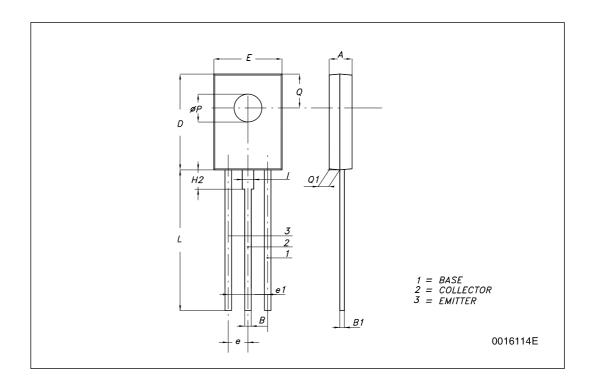
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

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SOT-32 (TO-126) MECHANICAL DATA

DIM	mm.			
DIM.	MIN.	TYP	MAX.	
А	2.4		2.9	
В	0.64		0.88	
B1	0.39		0.63	
D	10.5		11.05	
E	7.4		7.8	
е	2.04	2.29	2.54	
e1	4.07	4.58	5.08	
L	15.3		16	
Р	2.9		3.2	
Q		3.8		
Q1	1		1.52	
H2		2.15		
I		1.27		



Revision history ST93003

5 Revision history

Table 5. Document revision history

Date	Revision	Changes
08-Jul-2008	3	Mechanical data has been updated.
08-Sep-2009	4	Updated packaging information Table 1 on page 1.
06-Dec-2010	5	Added Table 3: Thermal data on page 3.

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